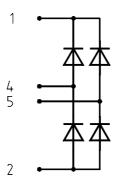


Silicon Carbide Schottky Rectifier Bridge in ISOPLUS i4-PAC™

FBS 16-06SC

 V_{RRM} = 600 V $I_{D(AV)M}$ = 11 A $C_{junction}$ = 21 pF





Rectifier Bridge					
Symbol	Conditions Maximum Rating				
V _{RRM}			600 V		
I _{FAV} I _{D(AV)M} I _{FSM}	$T_{\rm C} = 90^{\circ} C$	180° (per diode) 0 ms; sine 50 Hz	5 A 11 A 20 A		
P _{tot}	T _C = 25°C	(per diode)	27 W		

Symbol	Conditions	Characteristic Values (T _{VJ} = 25°C, unless otherwise specified)			
		min.	typ.	max.	
V _F	$I_F = 6 \text{ A};$	$T_{VJ} = 25^{\circ}C$ $T_{VJ} = 125^{\circ}C$	1.5 1.6	1.8	V
I _R	$V_R = V_{RRM};$	T _{VJ} = 25°C T _{VJ} = 125°C	0.05	0.2	mA mA
C	V _R = 400 V;	T _{VJ} = 125°C	21		pF
${\sf R}_{\sf thJC} \over {\sf R}_{\sf thJS}$	(per diode)		8.6	5.6	K/W K/W

Features

- Silicon Carbide Schottky Diodes
 - no reverse recovery at turn off only charge of junction capacity - soft turn off waveform
 - no forward recovery at turn on
- switching behaviour independent of temperature
- low leakage current
- ISOPLUS i4-PAC(TM) package
- isolated back surface
- low coupling capacity between pins and heatsink
- enlarged creepage towards heatsink
- application friendly pinout
- high reliability
- industry standard outline

Applications

- output rectifiers of high end switched mode power supplies
- other high frequency rectifiers

Data according to IEC 60747 and refer to a single diode unless otherwise stated.



Component					
Symbol	Conditions	Maximum Ratings			
T _{VJ} T _{stg}		-55+175 -55+125	°C		
V _{ISOL}	$I_{ISOL} \le 1 \text{ mA}$; 50/60 Hz	2500	V~		
F _c	mounting force with clip	20120	N		

Symbol	Conditions	Characteristic Values		
		min.	typ.	max.
C _p	coupling capacity between shorted pins and mounting tab in the case		40	pF
d_s, d_a d_s, d_a	pin - pin pin - backside metal	1.7 5.5		mm mm
Weight			9	g

